

FORM PTO-1449 SAMUELS, GAUTHIER & STEVENS LLP  
(Rev. 5/92) 225 Franklin Street, Boston, MA 02110  
Telephone: (617) 426-9180 ..

7042  
ATTORNEY DOCKET NO.

10/620,395  
SERIAL NO.

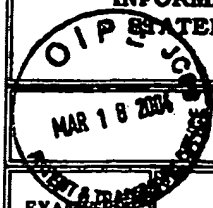
Zhang et al.  
APPLICANT

2816  
GROUP

07/16/2003  
FILING DATE

Unknown  
EXAMINER

**INFORMATION DISCLOSURE  
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**U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	AA						
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**FOREIGN PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
AT	AG	WO 02/067451	08/29/2002	PCT			YES (Abstract only)
	AH	0 700 161 A2	03/06/1999	EP			YES
	AI	09238059	09/09/1997	JP			YES (Abstract only)

**OTHER DOCUMENTS** (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER INITIAL		
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**U.S. PATENT DOCUMENTS**

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EXAMINER INITIAL	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
AT	AG	0766396	04/02/1997	EP		YES
	AH					
	AI					

**OTHER DOCUMENTS** (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER INITIAL		
AT	AJ	"Voltage-Tolerant Monolithic L-Band GaAs SPDT Switch," Cooper et al., <i>IEEE MTT-S Digest</i> (1989). No month
AT	AK	"A Dual-Gate Shorted-Anode Silicon-on-Insulator Lateral Insulated Gate Bipolar Transistor with Floating Ohmic Contact for Suppressing Snapback and Fast Switching Characteristics," Oh et al., <i>Microelectronics Journal</i> 30 pp. 577-581 (1999). No month
	AL	
	AM	
	AN	
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FORM PTO-1449 SAMUELS, GAUTHIER & STEVENS LLP (Rev. 5/92) 225 Franklin Street, Boston, MA 02110 Telephone: (617) 426-9180  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>		<b>7042</b> ATTORNEY DOCKET NO.  <u>Zhang et al.</u> APPLICANT  <u>Herewith</u> FILING DATE	Unknown SERIAL NO. <b>10620395</b>  Unknown GROUP  Unknown EXAMINER
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U.S. PATENT DOCUMENTS							
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FOREIGN PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES NO
<b>AT</b>	AG	WO 01/67602	09/13/2001	PCT			YES
	AH						
	AI						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)							
EXAMINER INITIAL							
<b>AT</b>	AJ	"High-Performance GaAs Switch IC's Fabricated Using MESFET's with Two Kinds of Pinch-Off Voltages and a Symmetrical Pattern Configuration," Uda et al. <i>IEEE Journal of Solid-State Circuits</i> . October 1994. Vol. 29, No. 10.					
	AK	"A Low-Voltage, High-Power T/R-Switch MMIC Using LC Resonators," Tokumitsu et al. <i>IEEE Transactions on Microwave Theory and Techniques</i> . May 1995. Vol. 43, No. 5.					
	AL	"A GaAs High-Power RF Single-Pole Double-Throw Switch IC for Digital Mobile Communication System," Miyatsuji et al. <i>IEEE International Solid-State Circuit Conference</i> . 1994. <i>Not mentioned</i>					
	AM	"Novel High Performance SPDT Power Switches Using Multi-Gate FET's," McGrath et al. <i>IEEE MTT-S Digest</i> . 1991. <i>Not mentioned</i>					
	AN	"A 3V MMIC Chip Set for 1.9GHz Mobile Communication Systems," Tanaka et al. <i>IEEE International Solid-State Circuits Conference</i> . 1995. <i>Not mentioned</i>					
	AO	"A High Power 2-18 GHz T/R Switch," Schindler et al. <i>IEEE MTT-S Digest</i> . 1990. <i>Not mentioned</i>					

EXAMINER <b>[Signature]</b>	DATE CONSIDERED <b>11/18/04</b>
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